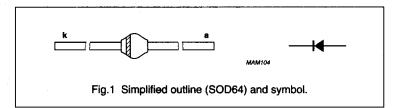
### **BYW97 series**

#### **FEATURES**

- · Glass passivated
- High maximum operating temperature
- · Low leakage current
- · Excellent stability
- Guaranteed avalanche energy absorption capability
- · Available in ammo-pack
- Also available with preformed leads for easy insertion.

#### **DESCRIPTION**

Rugged glass package, using a high temperature alloyed construction. This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>RRM</sub>	repetitive peak reverse voltage BYW97F BYW97G		<del>-</del>	1200 1400	v
V <sub>R</sub>	continuous reverse voltage BYW97F BYW97G		-	1200 1400	v v
I <sub>F(AV)</sub>	average forward current	T <sub>tp</sub> = 50 °C; lead length = 10 mm see Fig.2; averaged over any 20 ms period; see also Fig.6		3.3	A
I <sub>F(AV)</sub>	average forward current	T <sub>amb</sub> = 55 °C; PCB mounting (see Fig.11); see Fig.3; averaged over any 20 ms period; see also Fig.6	_	1.3	A
I <sub>FRM</sub>	repetitive peak forward current	T <sub>tp</sub> = 50 °C; see Fig.4		33	Α
		T <sub>amb</sub> = 55 °C; see Fig.5	_	13	Α
I <sub>FSM</sub>	non-repetitive peak forward current	t = 10 ms half sine wave; T <sub>j</sub> = T <sub>j max</sub> prior to surge; V <sub>R</sub> = V <sub>RRMmax</sub>	_	60	A
E <sub>RSM</sub>	non-repetitive peak reverse avalanche energy	L = 120 mH; $T_j = T_{j \text{ max}}$ prior to surge; inductive load switched off	-	10	mJ
T <sub>stg</sub>	storage temperature		65	+175	°C
T <sub>i</sub>	junction temperature	see Fig.7	-65	+175	∘C

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#### **ELECTRICAL CHARACTERISTICS**

T<sub>i</sub> = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V <sub>F</sub>	forward voltage	$I_F = 5 \text{ A}$ ; $T_j = T_{j \text{ max}}$ ; see Fig.8	_	_	1.25	V
		I <sub>F</sub> = 5 A; see Fig.8	-	_	1.45	٧
V <sub>(BR)R</sub>	reverse avalanche breakdown voltage	I <sub>R</sub> = 0.1 mA				
	BYW97F		1 300	_	-	V
	BYW97G		1500	_	_	v
I <sub>A</sub>	reverse current	V <sub>R</sub> = V <sub>RRMmax</sub> ; see Fig.9	-	<u>.</u> "	1	μА
		V <sub>R</sub> = V <sub>RRMmax</sub> ; T <sub>j</sub> = 165 °C; see Fig.9	-	-	150	μА
t <sub>rr</sub>	reverse recovery time	when switched from $I_F = 0.5$ A to $I_R = 1$ A; measured at $I_R = 0.25$ A; see Fig.12	_	-	500	ns
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 0 V; see Fig.10	_	65	_	pF
dl <sub>B</sub>    dt	maximum slope of reverse recovery current	when switched from $I_F = 1$ A to $V_R \ge 30$ V and $dI_F/dt = -1$ A/ $\mu$ s; see Fig.13		-	5	A/μs

#### THERMAL CHARACTERISTICS

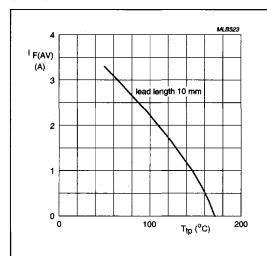
SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT	
R <sub>th j-tp</sub>	thermal resistance from junction to tie-point	lead length = 10 mm	25	K/W	
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	75	K/W	

#### Note

Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer ≥40 μm, see Fig.11.
For more information please refer to the 'General Part of Handbook SC01'.

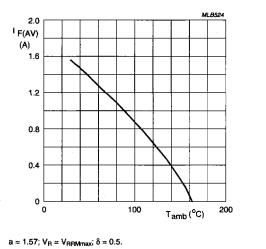
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#### **GRAPHICAL DATA**



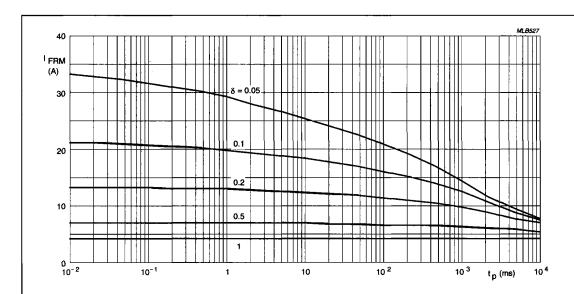
a = 1.57;  $V_R = V_{RRMmax}$ ;  $\delta = 0.5$ .

Fig.2 Maximum permissible average forward current as a function of tie-point temperature (including losses due to reverse leakage).



a = 1.57;  $V_R = V_{RRMmax}$ ;  $\delta = 0.5$ . Device mounted as shown in Fig.11.

Fig.3 Maximum permissible average forward current as a function of ambient temperature (including losses due to reverse leakage).



 $T_{tp} = 50$ °C;  $R_{th j-tp} = 25$  K/W.

 $V_{RRMmax}$  during 1 –  $\delta$ ; curves include derating for  $T_{j max}$  at  $V_{RRM}$  = 1400 V.

Fig.4 Maximum repetitive peak forward current as a function of pulse time (square pulse) and duty factor.

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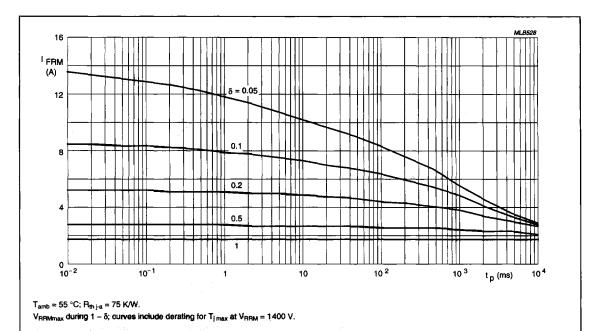
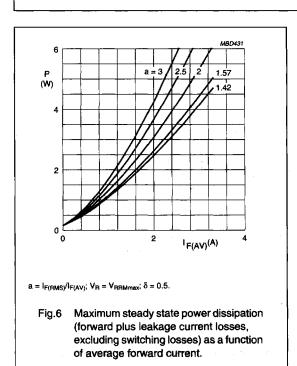
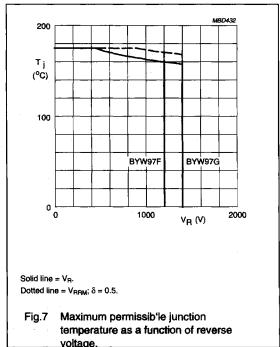
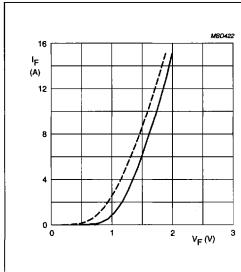


Fig.5 Maximum repetitive peak forward current as a function of pulse time (square pulse) and duty factor.



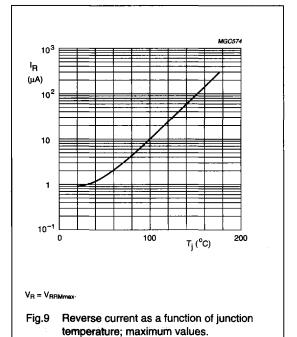


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Dotted line:  $T_j = 175$  °C. Solid line:  $T_j = 25$  °C.

Fig.8 Forward current as a function of forward voltage; maximum values.



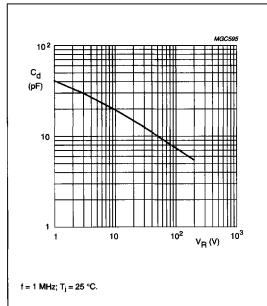
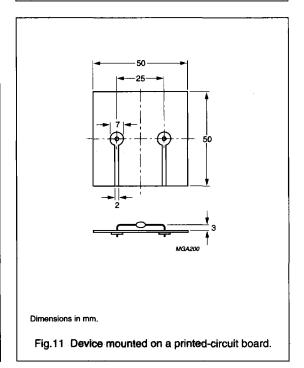


Fig.10 Diode capacitance as a function of reverse voltage; typical values.



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